

PUA3127 (PU3127)

Silicon NPN triple diffusion planar type

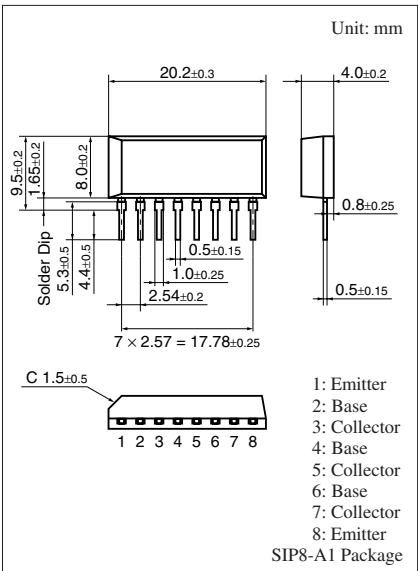
For power amplification/switching

■ Features

- High forward current transfer ratio h_{FE} which has satisfactory linearity
- NPN 3 elements

■ Absolute Maximum Ratings $T_C = 25^{\circ}\text{C}$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V_{CBO}	35 ± 5	V
Collector-emitter voltage (Base open)	V_{CEO}	35 ± 5	V
Emitter-base voltage (Collector open)	V_{EBO}	6	V
Collector current	I_C	3	A
Peak collector current	I_{CP}	6	A
Base current	I_B	1	A
Collector power dissipation	P_C	15	W
		$T_a = 25^{\circ}\text{C}$	
Junction temperature	T_j	150	$^{\circ}\text{C}$
Storage temperature	T_{stg}	-55 to $+150$	$^{\circ}\text{C}$

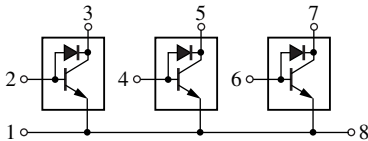


■ Electrical Characteristics $T_C = 25^{\circ}\text{C} \pm 3^{\circ}\text{C}$

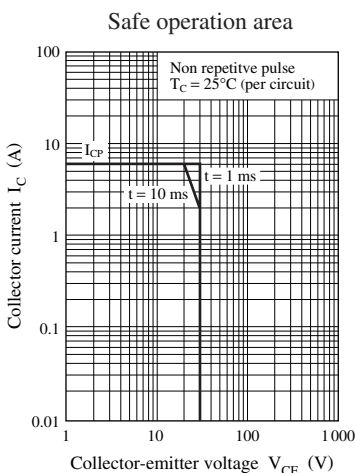
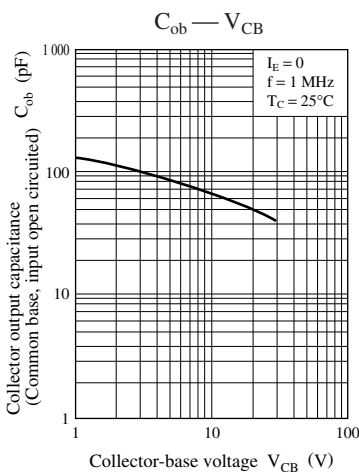
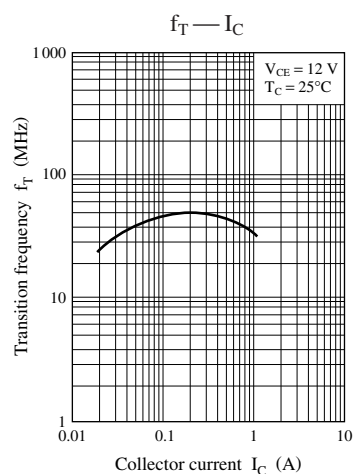
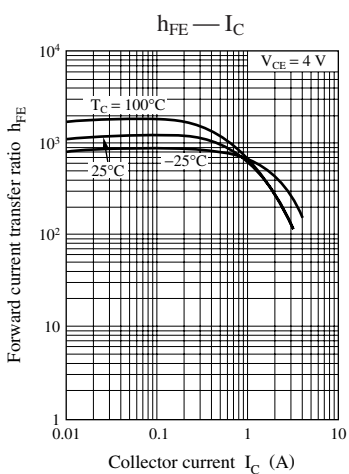
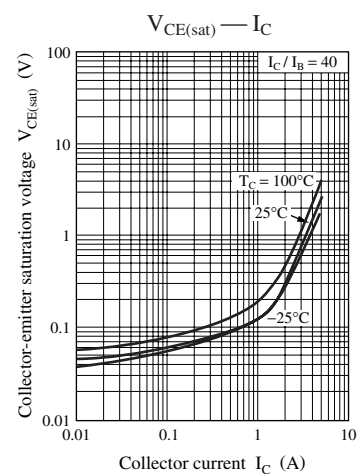
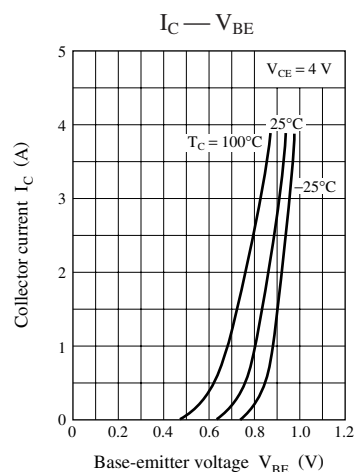
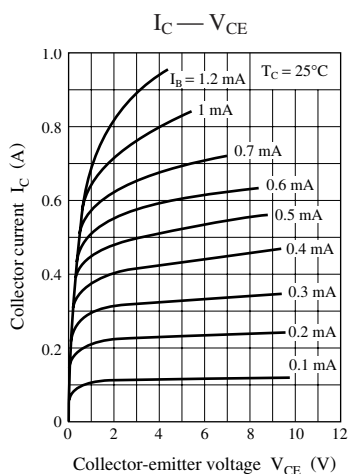
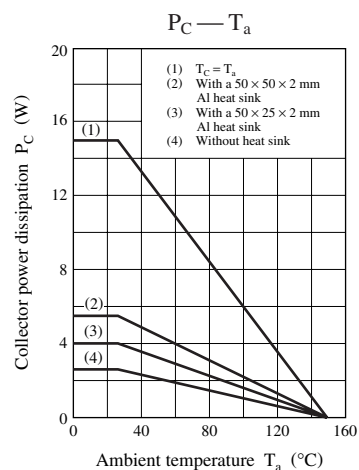
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-emitter voltage (Base open)	V_{CEO}	$I_C = 25 \text{ mA}, I_B = 0$	30		40	V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 30 \text{ V}, I_E = 0$			100	μA
Collector-emitter cutoff current (Base open)	I_{CEO}	$V_{CE} = 30 \text{ V}, I_B = 0$			100	μA
Emitter-base cutoff current (Collector open)	I_{EBO}	$V_{EB} = 6 \text{ V}, I_C = 0$			100	μA
Forward current transfer ratio	h_{FE}	$V_{CE} = 4 \text{ V}, I_C = 0.5 \text{ A}$	500		2500	—
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 2 \text{ A}, I_B = 0.05 \text{ A}$			1.0	V
Transition frequency	f_T	$V_{CE} = 12 \text{ V}, I_C = 0.2 \text{ A}, f = 10 \text{ MHz}$		50		MHz

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

■ Internal Connection



Note) The part number in the parenthesis shows conventional part number.



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